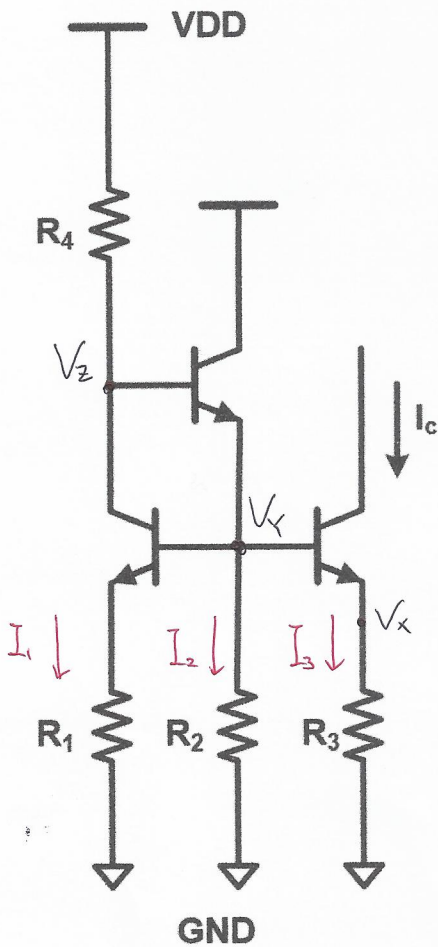


[1] Find the values of I_c . Assume that $R_1 = 1k\Omega$, $R_2 = 10k\Omega$, $R_3 = 1k\Omega$, $R_4 = 10k\Omega$, $V_{BE} = 0.7V$, $\beta = \infty$, and $V_{DD} = 10V$.



$$V_x = I_c R_3 = 1k \cdot I_c$$

$$V_z = 1k \cdot I_c + 2 \cdot V_{BE} = 1k \cdot I_c + 1.4 \quad \left. \begin{array}{l} 5 \\ 2 \end{array} \right\}$$

$$= V_{DD} - I_c R_4 = 10 - 10k \cdot I_c$$

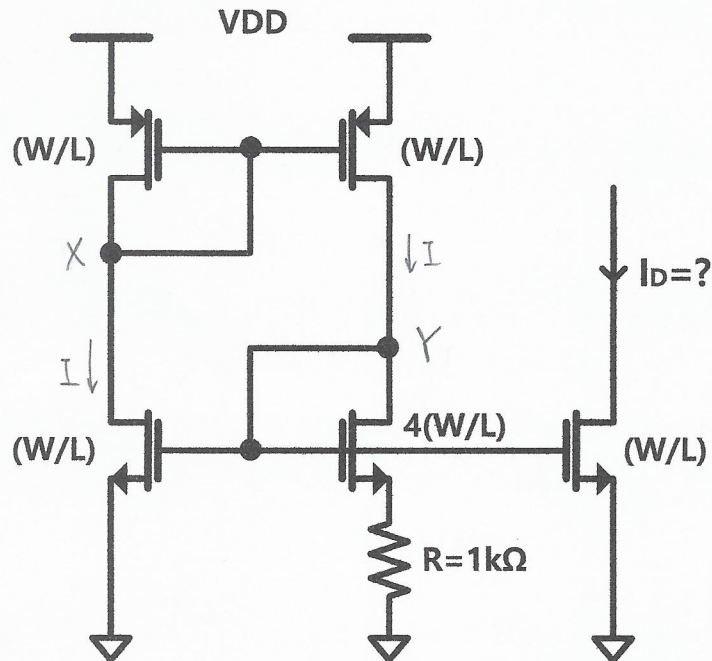
$$11k \cdot I_c = 8.6$$

$$\therefore I_c = \frac{8.6}{11} \text{ mA}$$

$$\approx 0.782 \text{ mA} \quad \left. \begin{array}{l} 3 \end{array} \right\}$$

$I_1 = I_2 = I_3$ 크 높고 토크 경우 0점
 ($I_1 = I_3 \neq I_2$)
 (같다고 가정하고 들면 무슨 발생)

[2] Find the value of I_D . Assume that $\left(\frac{W}{L}\right) = 10$, $\mu_n C_{ox} = \mu_p C_{ox} = 200 \mu A/V^2$, $V_{th} = 0.5V$, $\lambda = 0$, and $V_{DD} = 2V$.



$$\text{KCL @ node X} : \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right) (V_Y - V_{th})^2 = \frac{1}{2} \mu_p C_{ox} \left(\frac{W}{L}\right) (2 - V_X - V_{th})^2 = I$$

$$\text{KCL @ node Y} : \frac{1}{2} \mu_n C_{ox} \cdot 4 \left(\frac{W}{L}\right) \cdot (V_Y - IR - V_{th})^2 = \frac{1}{2} \mu_p C_{ox} \left(\frac{W}{L}\right) (2 - V_X - V_{th})^2 = I \quad \text{+3}$$

위 식에 값을 대입하여 정리하면,

$$(1.5 - V_X)^2 = \underbrace{(V_Y - 0.5)^2}_{\text{①}} = 4 \cdot \underbrace{(V_Y - 1000I - 0.5)^2}_{\text{②}} = 1000 \cdot I$$

$$\text{①로부터 } V_Y - 0.5 = 2(V_Y - 1000I - 0.5)$$

$$\text{②의 } 1000I = (V_Y - 0.5)^2 \text{을 위 식에 대입하여 정리하면, } (2V_Y - 1)(V_Y - 1) = 0$$

$$V_Y = 0.5 \text{인 경우 } I = 0 \text{이 되므로 가능한 } V_Y = 1(V) \quad \text{+4}$$

$$\therefore I_D = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L}\right) \cdot (V_Y - V_{th})^2 = 0.25 \text{ (mA)} \quad \text{+3}$$

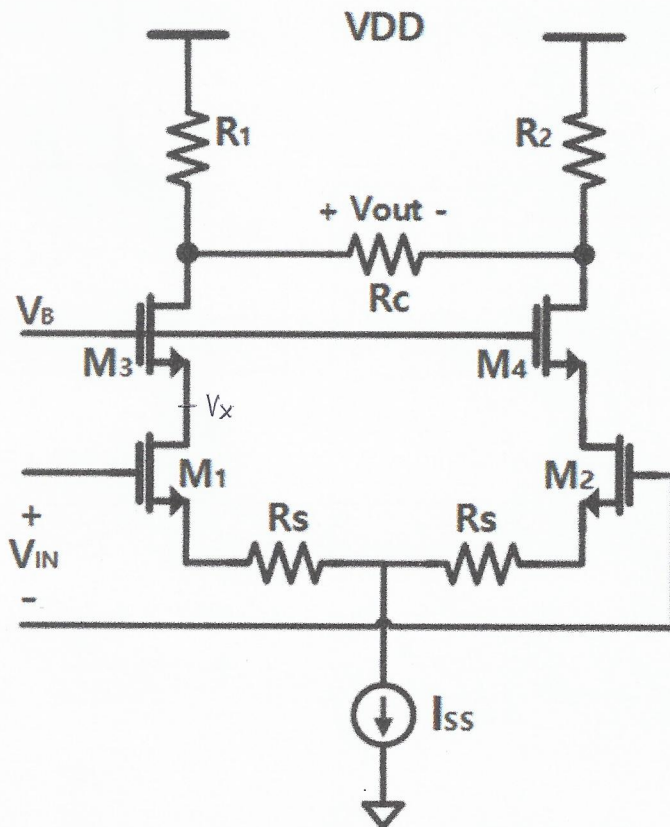
[3] For the following circuit, answer the questions.

Assume the circuit is symmetric and all MOS transistors are in the **saturation** region.

(Use $R_1=R_2=5k\Omega$, $R_c=20k\Omega$, $R_s=1k\Omega$, $V_{DD}=5V$, $I_{SS} = 1mA$, $V_{thn} = 0.4V$,

$g_{m1} = g_{m2} = 1 mA/V$, neglect the channel length modulation. M_1, M_2, M_3 and M_4 are ideally identical.

The V_{IN} is the small signal with common mode voltage ($V_{IN,CM}=2V$.)



* A번의 경우 문제에 오류가 있어 문제 재검토를 원하여 진행했습니다.

A. Find the V_B with the widest dynamic range of output.

$M_1 \rightarrow$ saturation.

$$g_m = \frac{2I_D}{V_{OV}} \Rightarrow 1mA/V = \frac{2 \cdot \frac{1}{2} \times 10^{-3} A}{V_{OV}}$$

$$\therefore V_{OV} = 1V$$

$M_1, M_2 \rightarrow$ ideally identical

$$M_1 \rightarrow V_{DS1} \geq V_{GS1} - V_{th}$$

$$\Rightarrow V_x \geq V_B - V_{th} = 1.6V$$

$$V_{OV} \geq V_B - V_{th}$$

$$V_B \geq V_x + V_{OV} + V_{th}$$

$$= 1.6 + 1 + 0.4 = 3V$$

$$V_B - V_{th} \leq V_{OV}$$

$$V_B \leq 2.4 \text{ 드 정상 범위}$$

* 재검시 위의 2차 방향으로 각각

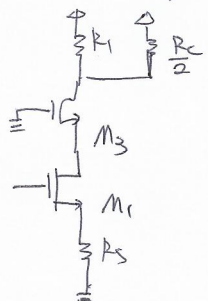
풀이시 출력 의도를 신경 댈면 2점 (부분점)

$V_B=2V$ 는 M_3 가 바에 OFF이므로 오답.

B. Derive the expression of small-signal differential voltage gain from V_{in} to V_{out} .

Consider the channel length modulation. There is no need to find a value.

half circuit analysis



$$A_{v} = -G_m \cdot R_{out}$$

$$= -\frac{g_{m1}}{1+g_{m1}R_s} \cdot \left(\frac{R_c || R_{11}}{2} \cdot g_{m1} \cdot g_{m3} \cdot r_{o1} \cdot r_{o3} \cdot R_s \right)$$

① 분모, $\frac{r_{out}}{V_{in}} \Rightarrow \ominus$ 1점.

② $G_m \rightarrow$ 2점.

③ $R_{out} \rightarrow$ 2점 총 5점

* R_{out} 의 경우 캐를 안해도 됨

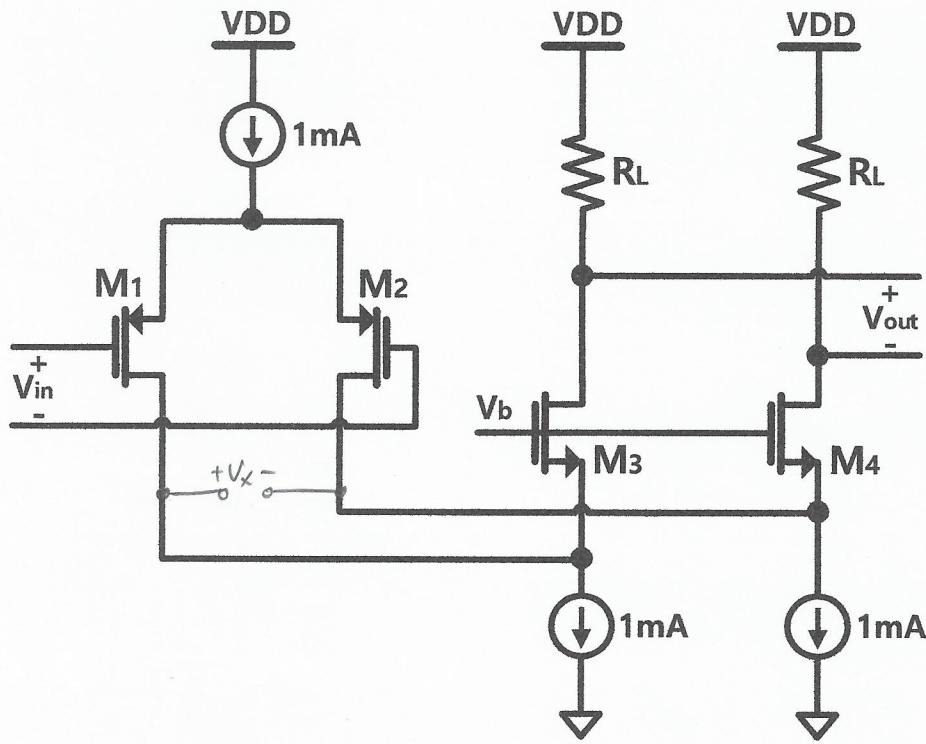
다만 channel length modulation을 고려하러 했기 때문

$r_o = \infty$ 등 경우는 오답

* 2 stage는 4점 문제 풀 경우 1 stage 당 2점.

2 stage 4점 + 분모 1점 = 5점

[4] Find the small signal gain $A_v (= \frac{V_{out}}{V_{in}})$. Assume that all transistors have the same $(\frac{W}{L})$ of 20, $\mu_n C_{OX} = 200 \mu A/V^2$, $\mu_p C_{OX} = 100 \mu A/V^2$, $V_{th} = 0.5V$, $\lambda_n = 0.01V^{-1}$, $\lambda_p = 0.02V^{-1}$, $R_L = 2k\Omega$, and $V_{DD} = 5V$. Also assume that all MOS transistors are in the saturation region.



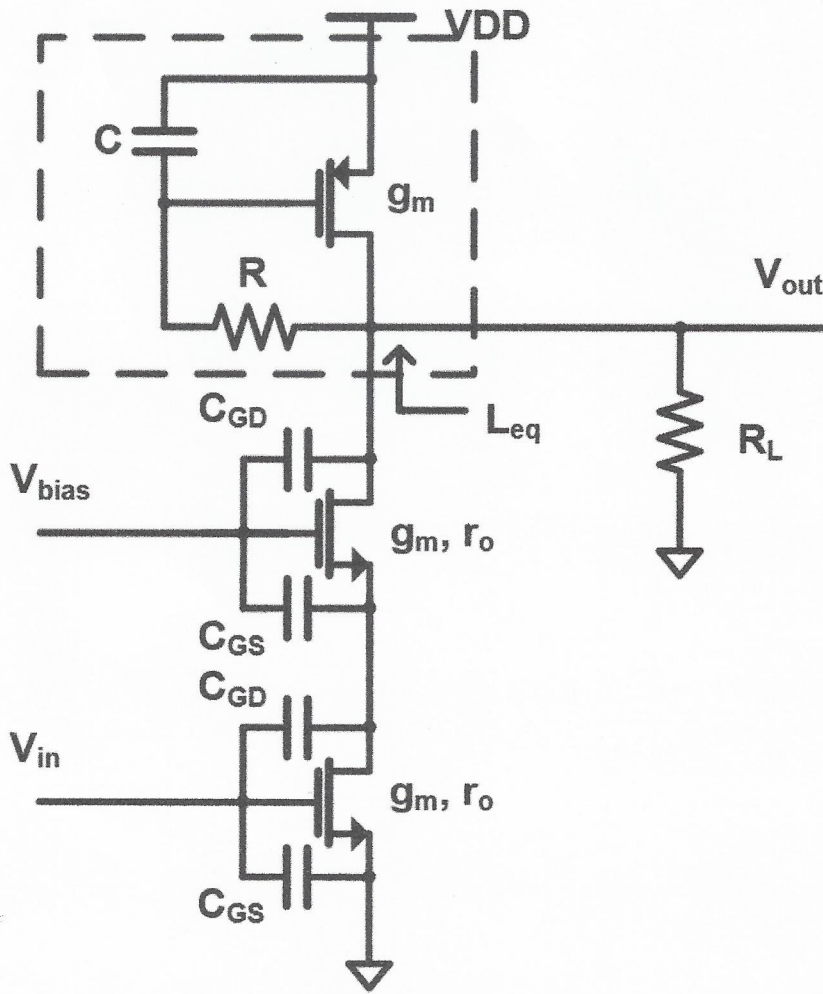
$$\left(\begin{aligned} g_{m1,2} &= \sqrt{2\mu_p C_{ox} \left(\frac{W}{L}\right) I_{D1}} = \sqrt{2} \text{ (mS)} \\ r_{o1,2} &= \frac{1}{\lambda_p I_{D1}} = 100 \text{ (k}\Omega) \end{aligned} \right) \quad \left(\begin{aligned} g_{m3,4} &= \sqrt{2\mu_n C_{ox} \left(\frac{W}{L}\right) I_{D3}} = 2 \text{ (mS)} \\ r_{o3,4} &= \frac{1}{\lambda_n I_{D3}} = 200 \text{ (k}\Omega) \end{aligned} \right)$$

$$\left\{ \begin{aligned} \frac{V_x}{V_{in}} &= -g_{m1} \cdot \left\{ \left(\frac{r_{o2} + R_L}{1 + g_{m3} r_{o2}} \right) \parallel r_{o1} \right\} \\ \frac{V_{out}}{V_x} &= g_{m3} (R_L \parallel r_{o3}) \end{aligned} \right.$$

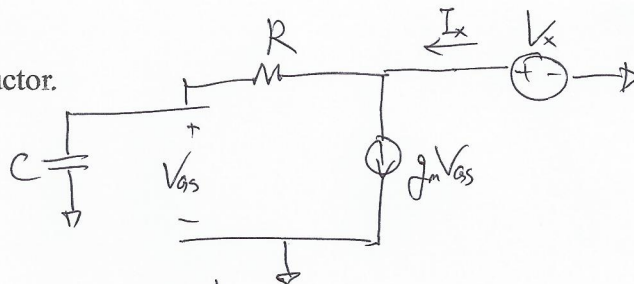
$$\begin{aligned} \frac{V_{out}}{V_{in}} &= -g_{m1} \cdot g_{m3} \cdot \left(\frac{r_{o2} + R_L}{1 + g_{m3} r_{o2}} \parallel r_{o1} \right) (R_L \parallel r_{o3}) \\ &\approx -2.81 \end{aligned}$$

gain 부호 틀릴 시 -1점.
 $\frac{V_x}{V_{in}} = -g_{m1} \cdot \frac{1}{g_{m3}}$ 로 근사하여 풀 경우 -2점.
 단, 근사에 대한 타당한 근거가 있을 시 정답 인정.

[5] For the following active inductor circuit, answer the questions.



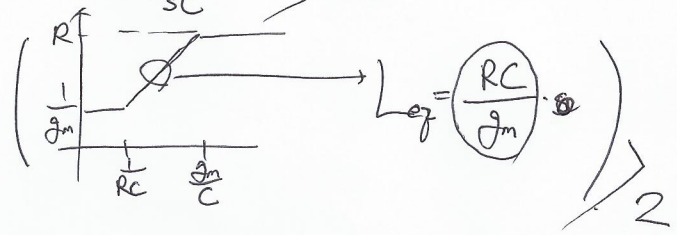
A. Find L_{eq} of the active inductor.



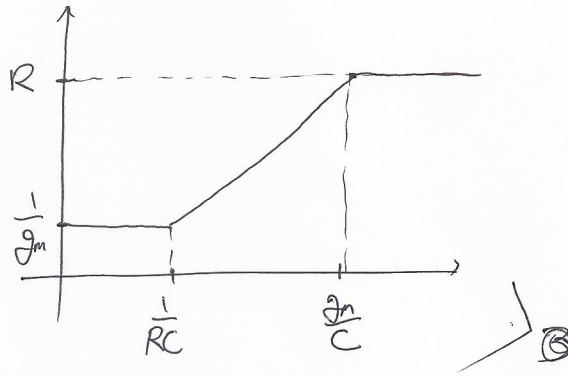
$$V_{gs} = \frac{\frac{1}{sC}}{R + \frac{1}{sC}} \cdot V_x$$

$$I_x = g_m V_{gs} + \frac{1}{R + \frac{1}{sC}} V_x = \frac{\frac{g_m}{sC} + 1}{R + \frac{1}{sC}} V_x \quad 3$$

$$Z_x = \frac{1 + sRC}{g_m + sC}$$



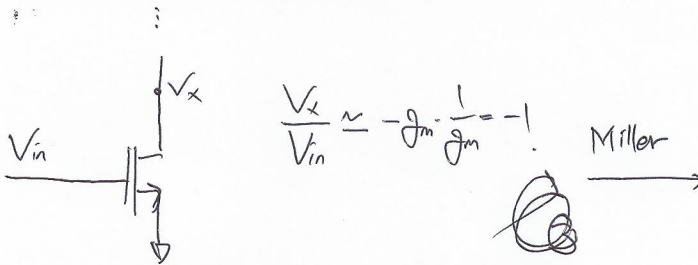
B. Find the frequency range where the active inductor becomes purely inductive.



$$\frac{1}{RC} < \omega < \frac{1}{C}$$

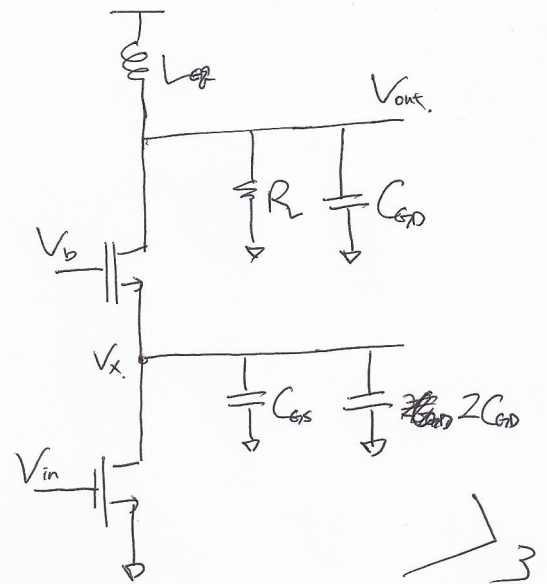
2 3

C. Find the transfer function of the above circuit.



$$\frac{V_x}{V_{in}} \approx -g_m \cdot \frac{1}{g_m} = -1$$

Miller

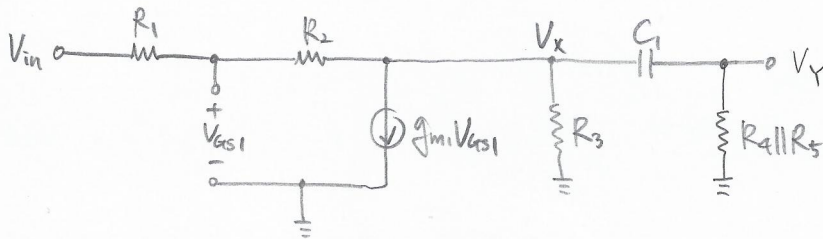
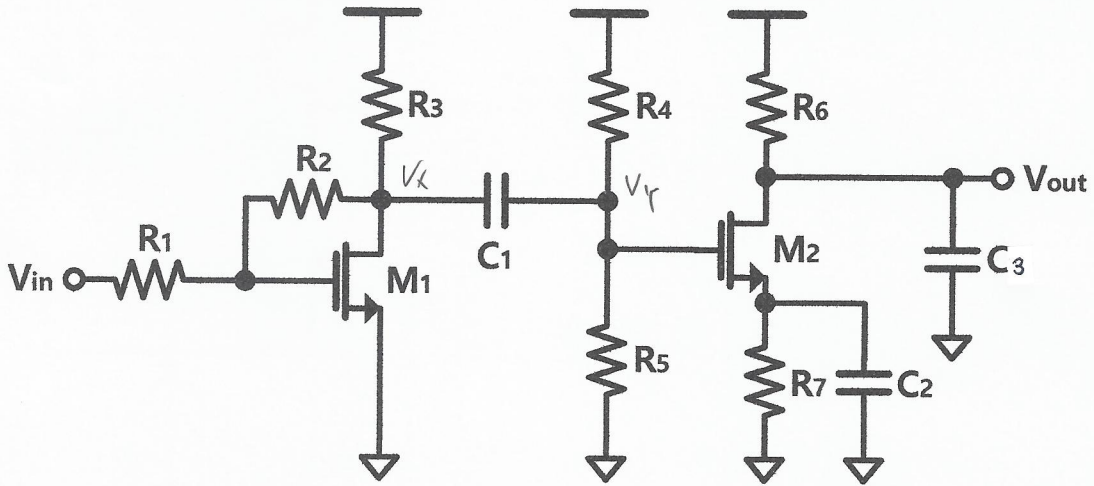


$$\frac{V_x}{V_{in}} = -g_m \left(\frac{1}{g_m} \parallel \frac{1}{s(C_{GS} + 2C_{GD})} \right)$$

$$\frac{V_{out}}{V_x} = g_m \left(sL_{eq} \parallel R_L \parallel \frac{1}{sC_{GD}} \right)$$

$$\frac{V_{out}}{V_{in}} = -g_m^2 \left(\frac{1}{g_m} \parallel \frac{1}{s(C_{GS} + 2C_{GD})} \right) \left(sL_{eq} \parallel R_L \parallel \frac{1}{sC_{GD}} \right)$$

[6] For the following circuit, find the transfer function $H(s)$ of the circuit and draw a Bode plot of $H(s)$. Assume that $R_1=R_2=R_3=1k\Omega$, $R_4=R_5=100k\Omega$, $R_6=2.5k\Omega$, $R_7=1k\Omega$, $C_1=2pF$, $C_2=4pF$, $C_3=4pF$, $g_{m1}=2mS$, $g_{m2}=4mS$.



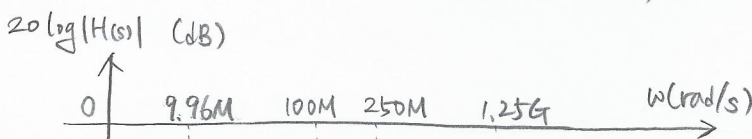
$$\begin{aligned}
 &g_{m1}V_{gs1} + \frac{V_x}{R_3} + sC_1(V_x - V_Y) + \frac{V_x - V_{gs1}}{R_2} = 0 \\
 &\frac{V_x - V_{gs1}}{R_2} = \frac{V_{gs1} - V_{in}}{R_1} \\
 &V_Y = \frac{(R_4 \parallel R_5)}{\frac{1}{sC_1} + (R_4 \parallel R_5)} \cdot V_x
 \end{aligned}$$

$$\Rightarrow \frac{V_Y}{V_{in}}(s) = - \frac{\frac{g_{m1}R_2 - 1}{R_1 + R_2}}{\frac{(g_{m1}R_2 - 1)R_1}{(R_1 + R_2)R_2} + \frac{1}{R_2} + \frac{1}{R_3} + \frac{1}{\frac{1}{sC_1} + (R_4 \parallel R_5)}} \cdot \frac{R_4 \parallel R_5}{\frac{1}{sC_1} + (R_4 \parallel R_5)}$$

$$= - \frac{s}{5 \times 10^7 (1 + s/(9.96 \times 10^6))}$$

$$\text{by } \pi \text{ rule, } \frac{V_{out}}{V_Y}(s) = - \frac{\frac{1}{sC_2} \parallel R_6}{\frac{1}{g_{m2}} + (\frac{1}{sC_2} \parallel R_7)} = - \frac{2(1 + s/(2.5 \times 10^8))}{(1 + s/(1.25 \times 10^9))(1 + s/10^8)}$$

$$\therefore H(s) = \frac{V_{out}}{V_{in}}(s) = \frac{V_x}{V_{in}}(s) \cdot \frac{V_Y}{V_x}(s) = \frac{4 \times 10^{-8} \cdot s \cdot (1 + s/(2.5 \times 10^8))}{(1 + s/(9.96 \times 10^6))(1 + s/(1.25 \times 10^9))(1 + s/10^8)}$$



$\uparrow +12$ ($\frac{V_x}{V_{in}} : 8 \text{ dB}$, $\frac{V_{out}}{V_Y} : 4 \text{ dB}$)
 $\uparrow +8$

- $\frac{1}{s}$ gain margin
- $\frac{1}{s}$ pole, zero position

[7] Fill in the table. Assume that $g_m = \infty$.

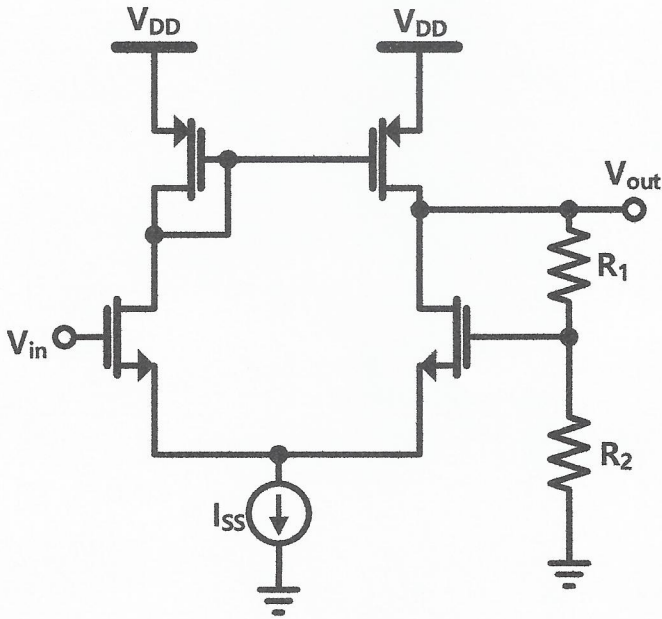


Fig A

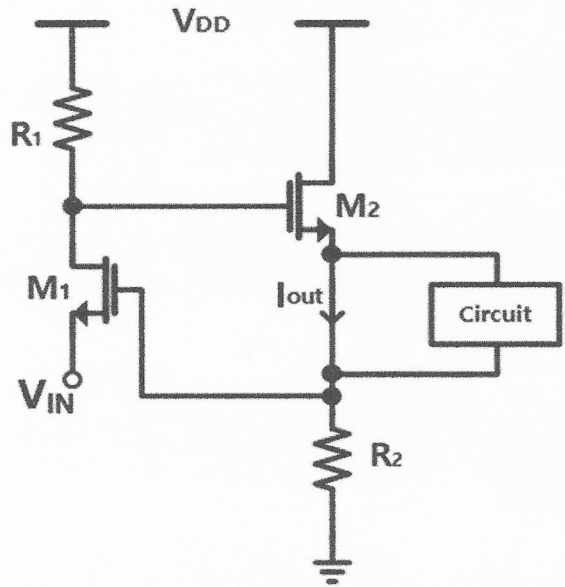


Fig B

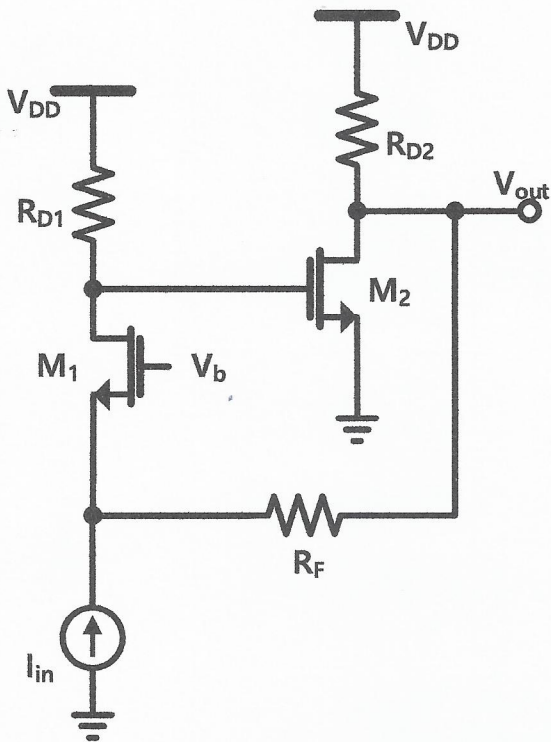


Fig C

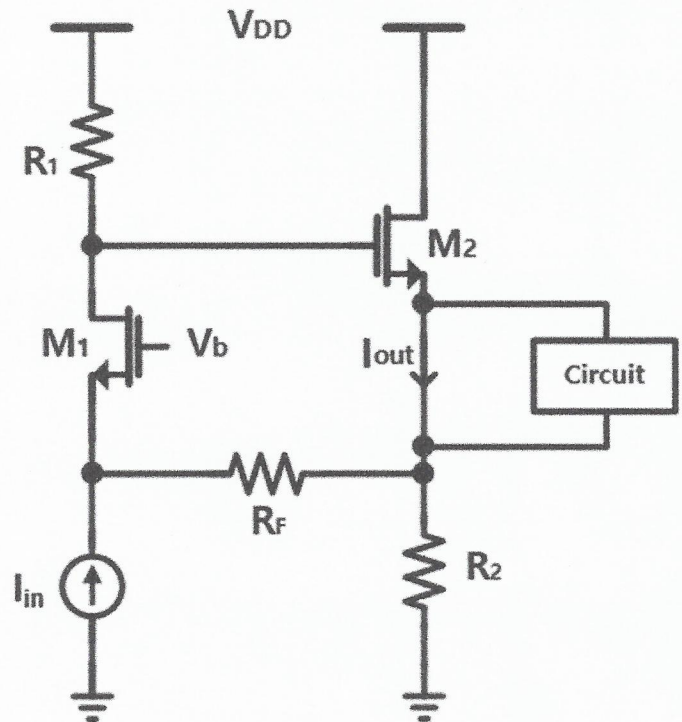


Fig D

	Fig A	Fig B	Fig C	Fig D
Feedback Topology	Voltage to Voltage	current to voltage	voltage to current	current to current
Type of Amplifier	voltage amp	trans conductance	trans impedance or trans resistance.	Current Amplifier
Open-loop Gain	∞	∞	$-\infty$	$\frac{R_1}{R_2 \parallel R_F}$
Feedback Factor	$\frac{R_2}{R_1 + R_2}$	R_2	$-\frac{1}{R_F}$	$\frac{-R_2}{R_F \parallel R_2}$
$R_{in-open}$	∞	0	0	0
$R_{in-closed}$	∞	R_1	0	0
$R_{out-open}$	$R_1 + R_2$ or $(R_1 + R_2) \parallel r_{on} \parallel r_{op}$	R_2	$R_2 \parallel R_F$ or $R_2 \parallel R_F \parallel r_{on}$	$R_2 \parallel R_F$
$R_{out-closed}$	0	∞	0	$(R_2 \parallel R_F) \cdot (1 - \frac{R_1}{R_F})$

{End of Midterm }

빈칸 한개당 1점

부호 틀리면 0점

$R_{out-open}$ 의 경우 $r_{on} = r_{op} = r_o$ 라 하고 채점.

ex) $r_o (R_1 + R_2) \parallel r_o \parallel r_o$ 도 되고

$(R_1 + R_2) \parallel r_o \parallel r_o$ 도 된다.